

Product Overview

BC846BPDW1: NPN PNP Bipolar Transistor

For complete documentation, see the data sheet.

The Dual NPN PNP Bipolar Transistor is designed for general purpose amplifier applications. It is housed in the SOT-363/SC-88 package, which is designed for low power surface mount applications.

Features

- Pb-Free Package is Available
- S and NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AECQ101 Qualified and PPAP Capable

Part Electrical Specifications

Product	Pricing (\$/Unit)	Compliance	Status	Polarity	Type	$V_{CE(sat)}$ Max (V)	I_C Cont. (A)	V_{CEO} Min (V)	V_{CBO} (V)	V_{EBO} (V)	$V_{BE(sat)}$ (V)	$V_{BE(0)}$ (V)	h_{FE} Min	h_{FE} Max	f_T Min (MHz)	P_{TM} Max (W)	Package Type
BC846BPDW1T1G	0.0279	Pb-free Halide free non AEC-Q and PPAP	Active	Complementary	General Purpose	0.6	0.1	65	80	6	0.7	0.66	200	475	100	0.38	SC-88-6 / SC-70-6 / SOT-363-6
SBC846BPDW1T1G	0.0565	AEC Qualified PPAP Capable Pb-free Halide free	Active	Complementary	General Purpose	0.6	0.1	65	80	6	0.7	0.66	200	475	100	0.38	SC-88-6 / SC-70-6 / SOT-363-6
SBC846BPDW1T2G	0.0565	AEC Qualified PPAP Capable Pb-free Halide free	Active	Complementary	General Purpose	0.6	0.1	65	80	6	0.7	0.66	200	475	100	0.38	SC-88-6 / SC-70-6 / SOT-363-6

For more information please contact your local sales support at www.onsemi.com.

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